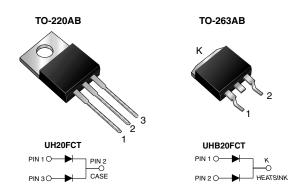




Vishay General Semiconductor

# **Dual Common-Cathode Ultrafast Recovery Rectifier**



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub> 10 A x 2					
$V_{RRM}$	300 V				
I <sub>FSM</sub>	180 A				
t <sub>rr</sub>	25 ns				
$V_{F}$	0.83 V				
T <sub>J</sub> max.	175 °C				

#### **FEATURES**

Oxide planar chip junction



· Ultrafast recovery times



Soft recovery characteristics

RoHS

• Low switching losses, high efficiency

· High forward surge capability

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

#### TYPICAL APPLICATIONS

For use in high frequency power factor correctors, switching mode power supplies, freewheeling diodes and secondary dc-to-dc rectification application.

#### **MECHANICAL DATA**

Case: TO-220AB and TO-263AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class

1A whisker test **Polarity:** As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER		SYMBOL	UH20FCT	UHB20FCT	UNIT		
Maximum repetitive peak reverse voltage		$V_{RRM}$	300		V		
Maximum average forward rectified current (see Fig.1)	per device per diode	I <sub>F(AV)</sub>	20 10		Α		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	per diode	I <sub>FSM</sub>	180		А		
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 175		°C		

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Maximum instantaneous forward voltage per diode <sup>(1)</sup>	I <sub>F</sub> = 5.0 A I <sub>F</sub> = 5.0 A	$T_J = 25 ^{\circ}\text{C}$ $T_J = 125 ^{\circ}\text{C}$	V <sub>F</sub>	0.96 0.77	-	· v	
	I <sub>F</sub> = 10 A I <sub>F</sub> = 10 A	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C		1.0 0.83	1.2 0.90		

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### **UH20FCT& UHB20FCT**

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Maximum reverse current per diode (2)	V <sub>R</sub> = 300 V	$T_J = 25 ^{\circ}\text{C}$ $T_J = 125 ^{\circ}\text{C}$	I <sub>R</sub>	0.5 25	5 150	μΑ	
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A},$ $I_{rr} = 0.25 \text{ A}$		t <sub>rr</sub>	20	25	ns	
Maximum reverse recovery time per diode	$I_F = 1.0 \text{ A}, \text{ dI/dt} = 50 \text{ A/}\mu\text{s}, \\ V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$		t <sub>rr</sub>	28	35	ns	
Typical softness factor (tb/ta)	$I_F = 10 \text{ A}, \text{ dI/dt} = 200 \text{ A/}\mu\text{s},$ $V_R = 200 \text{ V}, T_J = 125 ^{\circ}\text{C}$ per diode		S	0.36	-	=	
Typical reverse recovery current			I <sub>RM</sub>	7.0	-	Α	
Typical stored charge			$Q_{rr}$	160	-	nC	
Typical forward recovery time per diode	$I_F = 10 \text{ A}, \text{ dI/dt} = 80 \text{ A/}\mu\text{s},$ $V_{FR} = 1.1 \text{ x} V_{F \text{ max}}.$		t <sub>fr</sub>	150	-	ns	

#### Notes:

(1) Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq$  40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL UH20FCT UHB20FCT UNIT					
Typical thermal resistance per diode	$R_{ hetaJC}$	2.0	2.0	°C/W		

ORDERING INFORMATION							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	UH20FCT-E3/4W	1.88	4W	50/tube	Tube		
TO-263AB	UHB20FCT-E3/4W	1.38	4W	50/tube	Tube		
TO-263AB	UHB20FCT-E3/8W	1.38	8W	800/reel	Tape and reel		

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

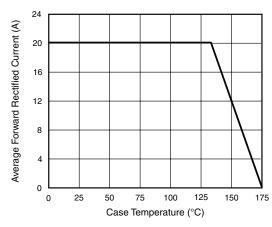


Figure 1. Maximum Forward Current Derating Curve

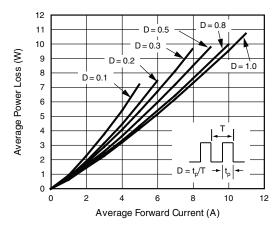


Figure 2. Forward Power Loss Characteristics Per Diode





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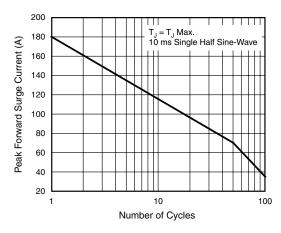


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

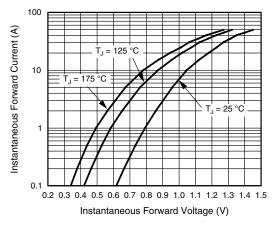


Figure 4. Typical Instantaneous Forward Characteristics Per Diode

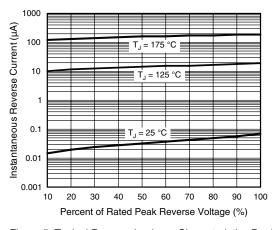


Figure 5. Typical Reverse Leakage Characteristics Per Diode

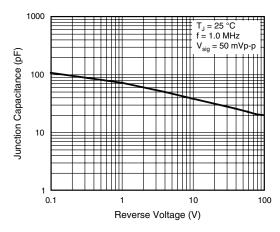


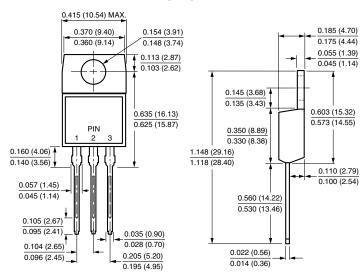
Figure 6. Typical Junction Capacitance Per Diode

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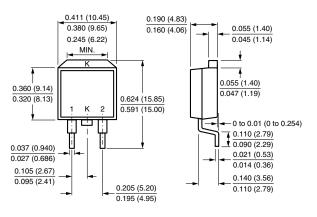


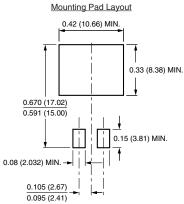
### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### **TO-220AB**



#### **TO-263AB**





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